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Wettability of 2519Al on B₄C at 1000–1250 °C and mechanical properties of infiltrated B₄C–2519Al composites

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Abstract

The wettability of 2519Al on boron carbide (B_4C) was investigated in detail by an improved sessile-drop method at temperature ranging from 1000 to 1250 °C. The interface reactions of B_4C –2519Al systems were analyzed by means of scanning electron microscopy (SEM), electron probe X-Ray microanalysis (EPMA) and X-ray diffraction (XRD). Typical flexural strength and hardness of infiltrated B_4C –2519Al composites were studied by three-point-bending tests and Rockwell hardness tester. It is found that the wettability and interaction between molten 2519Al alloy and B_4C are sensitive to the temperature and contact time. The contact angles significantly decreased and the solid–liquid interaction was more intense as the temperature increased. On the other hand, the formation of various compounds such as Al_3BC , $Al_3B_{48}C_2$ and AlB_2 was identified. Some Al_2Cu and Al_3Zr phases appeared in the 2519Al drop during cooling, while AlB_2 precipitated far away from the 2519Al/ B_4C interface. Ternary compounds of Al_3BC and $Al_3B_{48}C_2$, formed along the interface, play a key role in the improvement of wettability of $B_4C/2519Al$. For infiltrated 2519Al– B_4C composites, the typical bending strength and HRA are 300.71 MPa and 80.3, respectively. The main fracture way of infiltrated $B_4C/2519Al$ is transgranular rupture, which has smooth fracture surface and intrinsic brittle fracture mode. © 2013 Elsevier Ltd and Techna Group S.r.l. All rights reserved.

Keywords: C. Mechanical properties; Wetting; Contact angle; EPMA

1. Introduction

Boron carbide (B₄C) has a low density (2.52 g/cm³), a high hardness chemical potential, and high capacity for absorbing thermal neutron. Due to the outstanding properties, B₄C ceramics have great potential for many applications such as neutron absorber, blasting nozzles and especially light ceramic armor [1,2]. However, due to the strong covalent bonds, densification of stoichiometric boron carbide (B₄C) is extremely difficult. Moreover, the fracture toughness of B₄C ceramic is about 3.7 MPa m^{1/2}, which limited its applications in industrial applications [3].

It has been known that combining B_4C with a metal such as Al to B_4C -metal composites could improve the toughness of B_4C ceramic. B_4C -Al composites have the potential for offering a combination of high hardness and better toughness in a lightweight structure. There are several methods to fabricate the B_4C -Al composites or cermets, including powder

metallurgy, hot-press and pressureless infiltration. Among these methods, pressureless infiltration method, namely, infiltration molten Al into porous B₄C preforms under an inert atmosphere has been of more interest as a cost-effective method [4].

In the infiltration process of compositing, the feasibility for preparing materials and the performance of materials are largely determined by wetting behavior of molten aluminum on B₄C. Halverson [5] measured the contact angles of pure Al on B₄C based on sessile drops, finding that their contact angles at 1000 °C in the first 10min ranged from 104° to 80°. Naidich [6] reported that the contact angle of Al–B₄C is as high as 147° at 1000 °C, while it decreased sharply with increase in temperature and a value of 33° was obtained at 1150 °C after an isothermal dwell for 5min. Panasyuk [7] investigated the wetting kinetics of molten Al on the B₄C surfaces at 1100-1200 °C. It was found that their contact angle was initially 92° and then decreased to 28° in 3-5 min and the wetting was assumed to associate with the formation of an unknown compound in the contact zone. By using an improved sessile-drop method, Qiaoli Lin [8] reported that the contact angle of pure Al on boron carbide substrate are initially 56°

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and then decreased to 4° in 100 s at 1200 °C. For Al alloys on B_4C , Frage [9] investigated the effects of Al content in the Cu–Al and Sn–Al alloy on the wetting behavior of $B_4C/(Me-Al)$ systems, indicating that the wetting behavior is governed by the thermodynamic properties of the binary liquid system. On the other hand, the chemical reactivity of hot-pressed B_4C –Al was studied at temperatures ranging from 627 °C to 1000 °C [10]. It showed that at 868 °C, the reaction products are Al_3BC and AlB_2 . At temperatures higher than 868 °C, Al_3BC is still formed while $Al_3B_{48}C_2$ replaces some AlB_2 . However, Lee [11] and Arslan [12] considered that other phases, such as AlB_{12} ($Al_3B_{48}C_2$), AlB_{10} ($AlB_{24}C_4$), $AlB_{12}C_2$ and Al_4C_3 , can be formed in B_4C/Al composites, depending on the reaction temperature.

Compared to hot-pressed boron carbide, the hardness of B₄C-Al composites decreased because some relatively soft Al exists in the composites. In order to improve the hardness of the composites, Al alloy is a good choice to substitute pure Al as binder metal because of their hot treatment hardening effects. 2519Al (Al-5.8,Cu-0.3,Mn-0.2,Mg-0.2,Zr, mass fraction %) is a hard aluminum, which has been used as functionally graded armor plate [13,14]. Nevertheless, the wettability of 2519Al on B₄C has not been reported so far. In this study, the B₄C substrates were fabricated by the hotpress method, and the wetting behavior and interface reactions of B₄C/2519Al at temperatures from 1000-1250 °C were investigated using a modified sessile-drop method [15]. Moreover, the typical mechanical properties of B₄C-2519Al composites were studied. It showed that the wettability and interactions between 2519Al and B₄C were sensitive to the temperature and contact time. The contact angle significantly decreased and the solid-liquid interactions were more intense as the temperature increased.

2. Experimental

The B₄C substrates were prepared by hot pressing fine pure powder under inert atmosphere at 1800 °C and then pressureless sintering at 2100 °C. The boron carbide powders (average grain size of 5 µm) were milled and mixed in a planetary mill in methanol for 1 h using high-purity tungsten carbide balls. After drying at 100 °C, the powder mixtures were uniaxially cold pressed under 120 MPa into 50-mm inner diameter and 30-mm inner height samples in stainless steel mold. Green compacts were then hot-pressed in 50-mm diameter cylindrical double action graphite dies at 1800 °C under 20 MPa using HI-MVLTI-10000 graphite element furnace. Hot pressing sintering and heat treatment were carried out under Ar atmosphere using a heating rate of 10 °C/min. The sintered boron carbide bodies were cut to plate of Φ 20 mm \times 10 mm, surface ground on diamond disc and polished with diamond paste with the size of 5 µm and 2.5 µm, respectively. For optical microstructure examination, the polished surfaces were electrochemically etched in a 1% KOH solution with a current density of 0.03 A/cm² for 60–120 s [16,17].

The 2519Al sheets were prepared by starting materials of Al–50Cu, Al–Mn, Al–Zr and pure Mg. The alloys were melted

in a resistance furnace at 780 $^{\circ}$ C and casting at 730 $^{\circ}$ C in an iron die. After 525 $^{\circ}$ C \times 1 h solid solution treatment, the casting ingots were cold rolled and then aged at 165 $^{\circ}$ C for 16 h. Before wetting experiment, the 2519Al sheets were cut to what the experiment required, and the sheets were then ultrasonically cleaned in acetone.

An improved sessile-drop method which was called a dispensed sessile drop method, as described in detail elsewhere [15], was employed for the wetting experiments. In this method, the sessile drop was formed by extruding through a narrow orifice (1 mm diameter) of an alumina tube and dropping onto the substrate surface. In this case, the initial oxide on the Al surface can be mechanically removed and the measured contact angles are more accurate and closer to the true contact angles of the 2519Al/B₄C system. The main advantages of this modified method lie in that it enables the isothermal spreading kinetics to be fully monitored and that it eliminates the pre-interaction of the molten alloy with the substrate. The process of this experiment was to put the molten 2519A alloy on Al₂O₃ extrusion pipe of the experimental device initially, then vacuum the device, and then heated to the set temperature. A drop of alloy dripped on the substrate from the opening seized 1 mm on the front of Al₂O₃ extrusion pipe, after the insulation test accomplished, the sample was cooled to room temperature in the furnace. During wetting process, photos were taken at a speed of two frames per second using a high-resolution (1504 \times 1000 dpi) CCD camera. The contact angles and diameters of solid-liquid interface were computed by using axisymmetric drop shape analysis-profile software (ADSA-P) from shot photographs.

Three-point-bending tests were carried out to measure flexural strength of infiltrated B_4C –2519Al composites and the dimension of the bars was 35 mm \times 4 mm \times 3 mm with a support span of 30 mm. The flexural strength is given by the following equation:

$$\sigma_f = \frac{3FL}{2hh^2} \tag{1}$$

where F is the measured load at fracture (N), L is the support span distance (mm), b is the width of the specimen (mm), and b is the specimen thickness (mm). All tests were performed using an Instron 3369 mechanical testing machine under a crosshead speed of 0.5 mm/min. The hardness of the $B_4C-2519Al$ composites was evaluated by the Rockwell A indentations (HRA) using a standard A indentation tester The Rockwell A diamond stylus (cone apex angle 120° , tip radius R=0.2 mm) was used to perform the tests. The applied load on the stylus was $60 \, \mathrm{kg}$.

After the wetting and infiltrating experiments, the selected specimens were sectioned and polished for microstructure observation using field emission scanning electron microscopy (FE-SEM) (FEI nano230) and optical microscopy (Leica, MeF3A). The bulk density and porosity were determined by the Archimedes' method and bulk chemical compositions of phases were determined by electron probe X-ray microanalysis (EPMA, JXA-8530F). The crystalline phases were characterized by X-ray diffraction (XRD) (Rigaku 3014) technique by using CuK_{α} radiation.

3. Results

3.1. Microstructure of boron carbide substrate

The density of B_4C substrates used in the experiment is $2.29~g/cm^3$, and the sintered relative density is 91%. Fig. 1 shows the different magnifications of metallographs (Fig. 1a, b) and SEM images (Fig. 1c, d) of B_4C substrates. The specimens were both electrochemically etched using KOH dissolved in distilled water as the electrolyte. Most of the grain boundaries show bright contrast and samples are composed of equiaxed grains, which appear as straight and sharp grain boundaries. It shows a wide range of grain size extending from 6 μ m to 48 μ m. In addition, a low-density of crystal defects, such as twins, planar stacks were observed in the substrate.

It was well known that boron carbide has α -rhombohedral crystal structure [18–21], which is hard to slip in plastic deformation. During hot-pressing at high temperature up to 1800 °C, however, it deformed by mechanical twinning or growth twinning mode, which need higher deformation stored energy and may shear to the matrix. The nucleation and growth mechanism of these compression twins in boron carbide are not clear.

Two types of darker regions were viewed in the micrograph (Fig. 1a, b), one was large and connected holes, and the other was small stripe pores. The formation of these connected holes has not only resulted from the incomplete densification during sintering, but also due to the pull-out surface of boron carbide grain, which were left during metallographic sample preparation because of the low toughness of boron carbide. This can be recognized in the SEM images of Fig. 1c, d.

3.2. Contact angle

Fig. 2a shows the variations in contact angles with time for the molten 2519Al alloy on B_4C surfaces at 1000-1250 °C. Two representative sessile drop images at 1200 °C, which at moments of t=0 s and t=1800 s, are also shown in Fig. 2a. All the samples show a similar behavior of the contact angle versus time over the entire temperature range, and the contact angle depends on both the temperature and the time. The contact angles decreased rapidly in the initial several minutes and then approaches a steady value gradually, while the time needed to reach the steady value decreases with the increase in temperature. The initial contact angles are 111.5° (1000 °C), 103.9° (1100 °C), 79.6° (1200 °C) and 56.7° (1250 °C). The final contact angles reach 54.5° (1000 °C), 47.9° (1100 °C), 35.7° (1200 °C) and 34.5° (1250 °C) after 30 min of heat preservation.

Further analysis indicated that the temperature-dependent variation of initial contact angles at 1000–1250 °C follow an exponential decay law (Fig. 2b),

$$\theta_I = 116.94 - 0.00026 \exp(T/101.07)$$
 (2)

where θ_I is the initial contact angle, and T is the experiment temperature. This result is different from pure Al on boron carbide, which has a linear relationship in a temperature range of 900–1200 °C [8].

The final contact angles' dependence on temperature is described by the following linear relationship (Fig. 2b):

$$\theta_f = 141.2 - 0.086T \tag{3}$$

where T is the experiment temperature, and θ_f is the final contact angle at different temperature range.

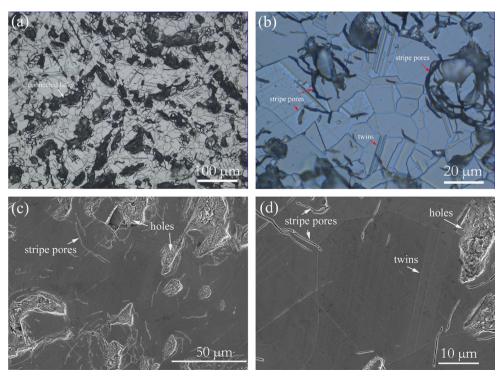


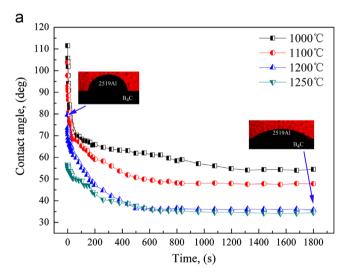
Fig. 1. Optical micrographs (a, b) and SEM images (c, d) of hot-press B₄C substrate.

As shown in Fig. 2b and Eqs. (2) and (3), the initial contact angles decrease relatively rapidly during temperature of $1000\,^{\circ}\text{C}$ – $1250\,^{\circ}\text{C}$. This may be related to the interfacial chemical reactions as well as the rupture of Al_2O_3 -membrane between the molten Al and B_4C , which will be discussed in the next chapter.

3.3. Interface microstructure

Fig. 3a shows the XRD patterns of $B_4C/2519Al$ at the surfaces of the solidified Al drops during $1000-1250\,^{\circ}C$. It is found that a great number of Al_2Cu and Al_3Zr phases were present at the drop surface, which precipitated during cooling. A representative XRD pattern of the interface tested at $1200\,^{\circ}C$ is shown in Fig. 3b. At temperature of $1200\,^{\circ}C$, large amounts of Al_3BC were identified. In addition, some $Al_3B_{48}C_2$, AlB_2 and Al_4C_3 compounds appeared at $1200\,^{\circ}C$.

Fig. 4 shows the cross-sectional secondary electron images of samples wetting at 1000 °C (Fig. 4a) and 1200 °C (Fig. 4c) after 30 min. Fig. 4b and d shows enlarged region of the block



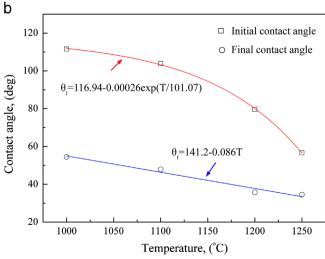
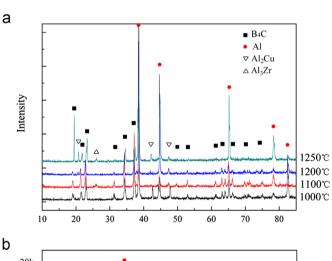


Fig. 2. (a) Variation in the contact angles with time for molten 2519Al on the B_4C substrate during 1000–1250 °C, and (b) variation in the initial and final contact angles with temperature.

in Fig. 4a and c. In combination with XRD and EDS analyses, the reaction products of Al_3BC and AlB_2 were identified in all the samples. As wetting temperature increased from 1000 °C to 1200 °C, the amount of Al_3BC phase increased. The AlB_2 phases, which have the morphology of rods or ribbon, were found to increase steadily with increasing temperature. According to the binary phase diagram of Al–Zr, the solubility of Zr in Al is close to 10 wt% in an equilibrium state of 1200 °C; therefore, the strengthening phases such θ , Al_3Zr in 2519Al will be re-dissolved into the Al liquid, and reprecipitated as coarse Al_2Cu and Al_3Zr phases during cooling.

The microstructure and phases of B₄C-2519Al samples were well revealed by the EPMA technique as shown in Fig. 5. It shows similar morphological features as those presented in Fig. 4, namely, with many boride crystals (AlB₂) grown in 2519Al drop and a rough B₄C surface covered by a layer of Al₃BC crystals (marked as "2"). Some large islands-like phases, presented at the interface (marked as "1"), were determined as Al₃B₄₈C₂ (β-AlB₁₂). By careful observations on the interfacial microstructures, a red layer, which has morphologies of coarse grains and are adjacent to theAl₃BC or Al₃B₄₈C₂ (Fig. 5b), were identified as Al₄C₃ phases (marked as "3" in Fig. 5a). It should be noted that the AlB₂



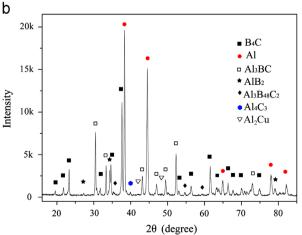


Fig. 3. XRD patterns of the B_4C –2519Al samples at the surfaces of the 2519Al drops (a) and the XRD patterns of the represented interfaces at 1200 $^{\circ}$ C (b).

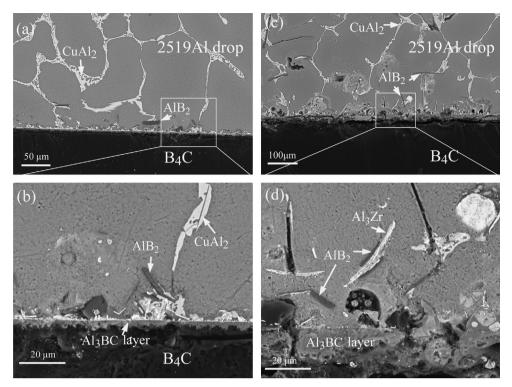


Fig. 4. SEM images of the B₄C-2519Al sample of the reaction interface with different experiment temperatures. (a, b) -1000 °C; and (c, d) -1200 °C.

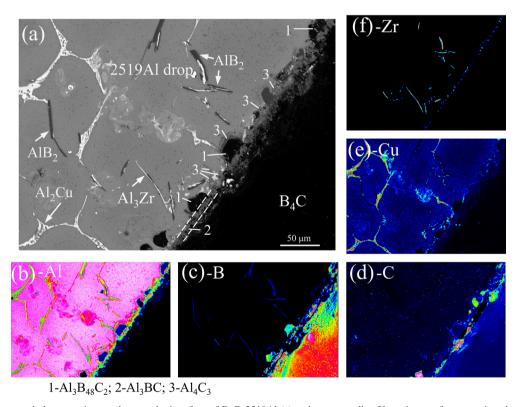


Fig. 5. EPMA backscattered electron micrographs near the interface of $B_4C-2519Al$ (a) and corresponding X-ray images for respective elements: (b) aluminum, (c) boron, (d) carbon, (e) copper and (f) zirconium.

phase is unstable at temperatures higher than 950 °C because of the peritectic transformation of $\alpha\text{-AlB}_{12}\text{+liquid} \rightarrow \text{AlB}_2$ [22] and the boron-rich $\alpha\text{-AlB}_{12}$ or $\text{Al}_3\text{B}_{48}\text{C}_2$ ($\beta\text{-AlB}_{12}$) phase present at the interface at $T \geq 950$ °C, and some of it transformed to AlB $_2$ during cooling.

3.4. Flexural strength and hardness of typical B_4C –2519Al composites

Fig. 6 shows a typical load–displacement curve for the B_4C –2519Al composites. The density of the composite is 2.62 g/cm^3

with 0.1% porosity. It was observed that the nearly fully dense composites have only elastic deformation with little displacement, indicating brittle fracture. The average flexural strength of five samples is about 300 MPa (Table 1), which is lower than that of HP-B₄C and SPS-B₄C (\sim 430 MPa) [1,2,31]. The average hardness of the samples is HRA 80.3 (Table 2), which is lower than pure B₄C. As shown in Fig. 7, the fracture surfaces were flat and the cracks appeared mainly in the transcrystalline form, partly in the intercrystalline form. Besides the matrix and the reinforcement, mechanical properties of ceramic-metal composites are also related to the density of complex and the interface reaction. For B₄C-Al composite, high volume fraction of boron carbide is carrying the main load. When bending load exceeds the elastic limit of boron carbide, the crack is formed at the interface and it propagated the boron carbide grains quickly, causing the composites failure. At 1200 °C infiltration process, Al₃BC phases formed along the interface between B₄C and Al, reducing the interfacial strength. As a result, the flexural strength is markedly decreased compared with pure B₄C.

4. Discussion

The effects of interface reaction on the wetting behavior of Al/B₄C and the wetting mechanism of it are still not clear or subject to controversy. Viala [10] and Arslan [12] consider that in Al/B₄C system the wetting seems to be associated with the formation of Al₃BC only. The formation of AlB₂ and AlB₁₂ phases plays limited effects on wetting because B₄C particles

are generally surrounded by Al_3BC crystals, while other crystals are most often embedded in the Al matrix, far away from the B_4C/Al reaction front. This result is in agreement with the work of Fujii [23] who did not detect uniformly distributed α -AlB₁₂ and AlB₂ crystals throughout the BN–Al interface.

However, in view of complex compound of $Al_{2.1}B_{51}C_8$ formed at the interface, Qiaoli Lin [8] and Kharlamov [24] consider that the wettability of B_4C by pure Al was determined by the formation of different reaction products, where the Al_3BC phase makes a considerable, yet limited, contribution to the wettability (contact angle 4°at 1200 °C after 100 s). The formation of the B-rich phases, particularly $Al_{2.1}B_{51}C_8$ (or $AlB_{24}C_4$), can more significantly improve their wettability.

The formation of the Al₃BC and AlB₂ phase in the B₄C/Al was described by Viala and Bouix [10] through a classical dissolution–precipitation mechanism. The molten Al rapidly saturated in B and C by simple dissolution of the boron carbide due to very low solubility of these elements in Al, and then the Al₃BC nucleated at the surface of B₄C. The AlB₂ phases nucleated with difficulty and were only embedded in the Al matrix as shown in Figs. 3 and 5, far away from the B₄C/Al reaction front. Through the interface reaction, the liquid melt is spread out in all directions and the wetting angles decreased significantly in the first 200 s (Fig. 2a). When Al₃BC crystals tend to join together and form a dense layer of B₄C surface, the substrate is protected against further attack. At this stage, further growth of reaction product crystals may obey another

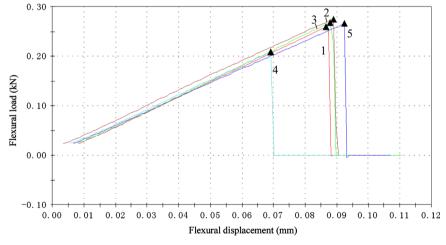


Fig. 6. The load-displacement curves for typical B₄C/2519Al composites under flexural testing.

Table 1 The flexural strength of typical infiltrated B_4C –2519Al composites.

Sample	Density (g/cm ³)	Maximum load F (N)	Bending strength σ_f (MPa)
1	2.62	258.66	301.30
2	2.62	275.06	320.40
3	2.62	268.02	330.60
4	2.62	207.86	242.12
5	2.62	265.48	309.24
Average	2.62	255.01	300.73

mechanism that implies solid-state diffusion of B, C or Al atoms through the growing Al₃BC layer. The solid-state diffusion through the Al₃BC layer has become rate controlling, where the decompose rate of B₄C decreases considerably, resulting in the wetting contact angles to have a stable value (Fig. 2a). The formation of the Al₃BC layer is temperature dependent because the dissolution and solid diffusion processes are thermally activated. Thus the spreading of melt is faster and the contact angle decreased with the increase in temperature (Fig. 2), while the final wettability does not vary significantly at T > 1200 °C.

The larger contact angles at T < 1000 °C are likely to be influenced by the oxide films present at the Al and B₄C surfaces When the temperature was at T > 1000 °C, a self-cleaning reaction of Al drop was formed [25]

$$4Al(1) + Al_2O_3(s) = 3Al_2O(g)$$
(4)

The exothermal reaction, which enhanced the temperature in extremely small regions, could accelerate the reaction process. This phenomenon, to a large extent, led to the fracture of

Al₂O₃-membrane between the molten Al and substrate. The direct contact between Al and B₄C was extraordinarily beneficial to the progressing of the reactions on the interface and decreases the interfacial energy.

The interaction of the melt with boron carbide leads to the dissolution of boron into the melt and the concomitant release of free carbon. However, the solubility of carbon in molten aluminum is extremely limited. When in excess of its solubility limit, some free carbons reacted with aluminum and forms Al_4C_3 phases, as shown in Fig. 5. With a further increase in temperature, the Al_3BC diffusion barrier might be disrupted to a large extent by the formation of $Al_3B_{48}C_2$ phase through the following reactions [22]:

$$\alpha - AlB_{12} + Al_3BC \Leftrightarrow Al_3B_{48}C_2 + L \tag{5}$$

The aluminum dodecaboride (α -AlB₁₂) has not been identified to exist in the final microstructure. However, according to the Al–B binary phase diagram [26], α -AlB₁₂ might have formed during the temperature at 1000–1250 °C. It is considered that [10] a point may be reached where the liquid Al–B solution is enriched in boron due to Al depletion such that no

Table 2 The Rockwell hardness of typical infiltrated B_4C -2519Al composites.

Point	Hardness (HRA)	Density (g/cm ³)
1	79	2.62
2	81.4	2.62
3	80.3	2.62
4	80.5	2.62
Average	80.3	2.62

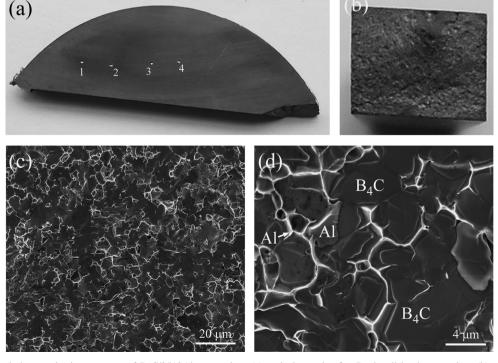


Fig. 7. The macro-morphology and microstructure of $B_4C/2519Al$ composites, (a) typical sample after Rockwell hardness testing, (b) typical bending fracture morphology of the $B_4C/2519Al$ sample, and corresponding fracture microstructure of the sample (c, d).

more boron can be dissolved leading to the precipitation of α -AlB₁₂. Such formed α -AlB₁₂ compounds then transform to AlB₂ during cooling by a peritectic reaction [22],

$$\alpha - AlB_{12} + L \Leftrightarrow AlB_2 \tag{6}$$

It is worth mentioning that the practical reactions and phase transformations in the 2519Al–B₄C system were more complicated from 1000 °C to 1250 °C since the decomposition of the Al₃BC [22]. Moreover, Kharlamov [24] and Lin [8] suggested that boron-rich phases of Al_{2.1}B₅₁C₈ or B₁₃C formed because the diffused rate of boron was faster than the Al in molten alloy. These boron-rich phases were broken down into several stable Al–B–C compounds, which could further expand the contact area between melt drop and B₄C substrate. Therefore, these compounds also make a great contribution to wettability.

In comparison to pure Al on B₄C [8], the final contact angles of 2519Al on B₄C have higher values of 35.7° (1200 °C) and 34.5° (1250 °C), greater than 4° for Al/B₄C at 1200 °C. This decrease of wetting behavior may be related to a copper element in the 2519Al alloy. Copper is generally regarded as non-reactive metal to B₄C, and its contact angle on B₄C ranges from 130 to 140° below 1800 °C [6,27]. Cu additions decrease the interface reaction or prohibit forming of a continuing layer of Al₃B₄₈C₂ and AlB₂₄C₄ [24], enlarge the surface tension γ_{lv} and plays a negative role on the wetting angle [28]. The equilibrium contact angle for the molten Al on the AlB₂₄C₄ (actually Al_{2.1}B₅₁C₈) phase, as reported by Kharlamov et al. [24], was 5° at 980 °C and that on the Al₃B₄₈C₂ phases was 12° at 1230 °C. On the other hand, the wettability of pure B by Al at 1000 °C is excellent with an equilibrium contact angle close to 0° [24] while the wettability of C or Al₄C₃ by molten Al is rather poor [29,30]. In this study, no AlB₂₄C₄ phases were distinguished by the EPMA and XRD techniques in the interfaces. It is reasonable to infer that the temperature dependence of the wettability of B₄C by molten 2519Al is essentially determined by the formation of different reaction products at the interface, especially the Al₃BC phase, while Al₃B₄₈C₂ phases makes a considerable, yet limited, contribution to the wettability. However, for pressureless infiltration fabricating the B₄C/2519Al composites, this wetting angle is enough. In actual infiltrating experiments, we found that almost full density of the B₄C/2519Al composites could be obtained at 1200 °C, which has about 35-volume percentage of 2519Al, as shown in Fig. 7.

5. Conclusion

In summary, the boron carbide substrate was prepared by hot pressing and pressureless sintering method and the wettability of B_4C by molten 2519Al at 1000–1250 °C was investigated by an improved sessile-drop method. The B_4C substrates are composed of equiaxed grains with a few crystal defects such as twins and pores. It is found that the wettability and interaction between molten 2519Al alloy and B_4C are quite sensitive to the temperature and contact time. The contact angle is significantly decreased as the temperature increased,

and the minimum values, namely, 34.5° are obtained after 30 min of heat preservation at 1250 °C. When the temperature is above 1000 °C, a direct reaction between Al drop and the B₄C substrate might occur because of the rupture of Al₂O₃ film. On the other hand, the gradually growing products at interfaces, such as Al₃BC and Al₃B₄₈C₂, could reduce the interfacial energy between solid and liquid, which enhance the wettibility. The Al₂Cu and Al₃Zr phases appeared in 2519Al matrix during cooling after experiment, while AlB₂ precipitated far away from the interface. For infiltrated B₄C/2519Al composites, the typical bending strength and hardness are 300.71 MPa and 80.3 HRA, respectively. The main fracture way of infiltrated B₄C/2519Al is transgranular rupture, which has flat fracture surface and intrinsic brittle fracture mode.

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